



# Quad SPDT ±15 V/+12 V Switches

## ADG1334

### FEATURES

- 33 V supply range
- 130 Ω on resistance
- Fully specified at ±15 V/+12 V
- 3 V logic compatible inputs
- Rail-to-rail operation
- Break-before-make switching action
- 20-lead SSOP

### APPLICATIONS

- Audio and video routing
- Battery-powered systems
- Signal routing

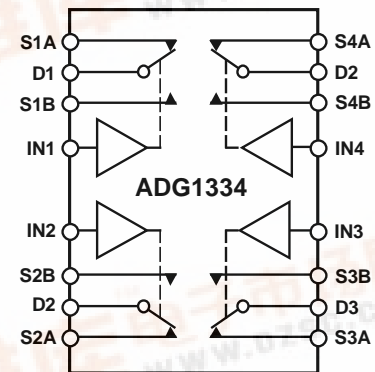
### GENERAL DESCRIPTION

The ADG1334 is a monolithic CMOS device comprising four independently selectable SPDT switches designed on a CMOS process.

When the switches are on, each switch conducts equally well in both directions and has an input signal range that extends to the power supplies. In the off condition, signal levels up to the supplies are blocked. All switches exhibit break-before-make switching action for use in multiplexer applications. Inherent in the design is the low charge injection for minimum transients when switching the digital inputs.

Fast switching speed coupled with high signal bandwidth makes the part suitable for video signal switching. CMOS construction ensures ultra low power dissipation, making the part ideally suited for portable and battery-powered instruments.

### FUNCTIONAL BLOCK DIAGRAM



SWITCHES SHOWN FOR A LOGIC 1 INPUT

Figure 1.

### PRODUCT HIGHLIGHTS

1. 3 V logic compatible digital input  $V_{IH} = 2.0\text{ V}$ ,  $V_{IL} = 0.8\text{ V}$ .
2. No  $V_L$  logic power supply required.
3. Low power consumption.
4. 20-lead SSOP.

05744-001



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**REVISION HISTORY**

**1/06—Revision 0: Initial Version**

## SPECIFICATIONS

### DUAL SUPPLY<sup>1</sup>

$V_{DD} = +15\text{ V} \pm 10\%$ ,  $V_{SS} = -15\text{ V} \pm 10\%$ ,  $GND = 0\text{ V}$ , unless otherwise noted.

Table 1.

| Parameter  | B Version   |                      | Unit              | Test Conditions/Comments   |
|--|-------------|----------------------|-------------------|--|
|  | +25°C       | -40°C to +105°C      |                   |  |
| <b>ANALOG SWITCH</b>                                     |             |                      |                   |  |
| Analog Signal Range                                      |             | $V_{SS}$ to $V_{DD}$ | V                 |  |
| On Resistance ( $R_{ON}$ )                               | 130         | 230                  | $\Omega$ typ      | $V_S = \pm 10\text{ V}$ , $I_S = -10\text{ mA}$ ; see Figure 11  |
|  | 200         |                      | $\Omega$ max      | $V_{DD} = +13.5\text{ V}$ , $V_{SS} = -13.5\text{ V}$  |
| On Resistance Match Between Channels ( $\Delta R_{ON}$ ) | 5           |                      | $\Omega$ typ      | $V_S = \pm 10\text{ V}$ , $I_S = -10\text{ mA}$  |
|  | 10          |                      | $\Omega$ max      |  |
| On Resistance Flatness ( $R_{FLAT(ON)}$ )                | 25          |                      | $\Omega$ typ      | $V_S = -5\text{ V}, 0\text{ V}, +5\text{ V}$ ; $I_S = -10\text{ mA}$   |
|  | 65          |                      | $\Omega$ max      |  |
| <b>LEAKAGE CURRENTS</b>                                  |             |                      |                   |  |
| Source Off Leakage $I_S$ (Off)                           | $\pm 10$    |                      | nA typ            | $V_{DD} = +16.5\text{ V}$ , $V_{SS} = -16.5\text{ V}$<br>$V_D = \pm 10\text{ V}$ ; $V_S = \pm 10\text{ V}$ ; see Figure 12 |
| Drain Off Leakage $I_D$ (Off)                            | $\pm 10$    |                      | nA typ            | $V_D = \pm 10\text{ V}$ ; $V_S = \pm 10\text{ V}$ ; see Figure 12  |
| Channel On Leakage $I_D, I_S$ (On)                       | $\pm 10$    |                      | nA typ            | $V_S = V_D = \pm 10\text{ V}$ ; see Figure 13  |
| <b>DIGITAL INPUTS</b>                                    |             |                      |                   |  |
| Input High Voltage, $V_{INH}$                            |             | 2.0                  | V min             |  |
| Input Low Voltage, $V_{INL}$                             |             | 0.8                  | V max             |  |
| Input Current, $I_{INL}$ or $I_{INH}$                    | $\pm 0.005$ |                      | $\mu\text{A}$ typ | $V_{IN} = V_{INL}$ or $V_{INH}$  |
|  |             | $\pm 0.1$            | $\mu\text{A}$ max |  |
| Digital Input Capacitance, $C_{IN}$                      | 5           |                      | pF typ            |  |
| <b>DYNAMIC CHARACTERISTICS<sup>2</sup></b>               |             |                      |                   |  |
| $T_{ON}$   | 110         |                      | ns typ            | $R_L = 300\ \Omega$ , $C_L = 35\text{ pF}$   |
|  | 130         | 150                  | ns max            | $V_S = 10\text{ V}$ ; see Figure 14  |
| $T_{OFF}$  | 65          |                      | ns typ            | $R_L = 300\ \Omega$ , $C_L = 35\text{ pF}$   |
|  | 85          | 95                   | ns max            | $V_S = 10\text{ V}$ ; see Figure 14  |
| $T_{BBM}$  | 25          |                      | ns typ            | $R_L = 300\ \Omega$ , $C_L = 35\text{ pF}$   |
|  |             | 10                   | ns min            | $V_{S1} = V_{S2} = +10\text{ V}$ ; see Figure 15   |
| Charge Injection   | 2           |                      | pC typ            | $V_S = 0\text{ V}$ , $R_S = 0\ \Omega$ , $C_L = 1\text{ nF}$ ; see Figure 16   |
| Off Isolation  | 80          |                      | dB typ            | $R_L = 50\ \Omega$ , $C_L = 5\text{ pF}$ , $f = 1\text{ MHz}$ ; see Figure 17  |
| Channel-to-Channel Crosstalk                             | 85          |                      | dB typ            | $R_L = 50\ \Omega$ , $C_L = 5\text{ pF}$ , $f = 1\text{ MHz}$ ; see Figure 19  |
| -3 dB Bandwidth  | 700         |                      | MHz typ           | $R_L = 50\ \Omega$ , $C_L = 5\text{ pF}$ ; see Figure 18   |
| $C_S$ (Off)  | 5           |                      | pF typ            | $f = 1\text{ MHz}$ ; $V_S = 0\text{ V}$  |
| $C_D$ (Off)  | 5           |                      | pF typ            | $f = 1\text{ MHz}$ ; $V_S = 0\text{ V}$  |
| $C_D, C_S$ (On)  | 10          |                      | pF typ            | $f = 1\text{ MHz}$ ; $V_S = 0\text{ V}$  |
| <b>POWER REQUIREMENTS</b>                                |             |                      |                   |  |
| $I_{DD}$   | 0.002       |                      | $\mu\text{A}$ typ | $V_{DD} = +16.5\text{ V}$ , $V_{SS} = -16.5\text{ V}$<br>Digital inputs = 0 V or $V_{DD}$                                  |
|  |             | 1                    | $\mu\text{A}$ max |  |
| $I_{DD}$   | 260         |                      | $\mu\text{A}$ typ | Digital inputs = 5 V   |
|  |             | 400                  | $\mu\text{A}$ max |  |
| $I_{SS}$   | 0.002       |                      | $\mu\text{A}$ typ | Digital inputs = 0 V or $V_{DD}$   |
|  |             | 1                    | $\mu\text{A}$ max |  |
| $I_{SS}$   | 0.002       |                      | $\mu\text{A}$ typ | Digital inputs = 5 V   |
|  |             | 1                    | $\mu\text{A}$ max |  |

<sup>1</sup> Temperature range is B Version: -40°C to +105°C.

<sup>2</sup> Guaranteed by design, not subject to production test.

# ADG1334

## SINGLE SUPPLY<sup>1</sup>

$V_{DD} = 12\text{ V} \pm 10\%$ ,  $V_{SS} = 0\text{ V}$ ,  $GND = 0\text{ V}$ , unless otherwise noted.

**Table 2.**

| Parameter  | B Version   |                 | Unit              | Test Conditions/Comments  |
|--|-------------|-----------------|-------------------|---|
|  | +25°C       | -40°C to +105°C |                   |   |
| <b>ANALOG SWITCH</b>                                     |             |                 |                   |   |
| Analog Signal Range                                      |             | 0 to $V_{DD}$   | V                 |   |
| On Resistance ( $R_{ON}$ )                               | 325         | 520             | $\Omega$ typ      | $V_S = 0\text{ V to }10\text{ V}$ , $I_S = -10\text{ mA}$ ; see Figure 11                                   |
|  | 500         |                 | $\Omega$ max      | $V_{DD} = 10.8\text{ V}$ , $V_{SS} = 0\text{ V}$  |
| On Resistance Match Between Channels ( $\Delta R_{ON}$ ) | 10          |                 | $\Omega$ typ      | $V_S = 0\text{ V to }10\text{ V}$ , $I_S = -10\text{ mA}$   |
|  | 20          |                 | $\Omega$ max      |   |
| On Resistance Flatness ( $R_{FLAT(ON)}$ )                | 65          |                 | $\Omega$ typ      | $V_S = 3\text{ V, }6\text{ V, }9\text{ V}$ , $I_S = -10\text{ mA}$  |
| <b>LEAKAGE CURRENTS</b>                                  |             |                 |                   |   |
| Source Off Leakage $I_S$ (Off)                           | $\pm 10$    |                 | nA typ            | $V_{DD} = 13.2\text{ V}$<br>$V_S = 1\text{ V/}10\text{ V}$ , $V_D = 10\text{ V/}1\text{ V}$ ; see Figure 12 |
| Drain Off Leakage $I_D$ (Off)                            | $\pm 10$    |                 | nA typ            | $V_S = 1\text{ V/}10\text{ V}$ , $V_D = 10\text{ V/}1\text{ V}$ ; see Figure 12                             |
| Channel On Leakage $I_D$ , $I_S$ (On)                    | $\pm 10$    |                 | nA typ            | $V_S = V_D = 1\text{ V or }10\text{ V}$ ; see Figure 13   |
| <b>DIGITAL INPUTS</b>                                    |             |                 |                   |   |
| Input High Voltage, $V_{INH}$                            |             | 2.0             | V min             |   |
| Input Low Voltage, $V_{INL}$                             |             | 0.8             | V max             |   |
| Input Current, $I_{INL}$ or $I_{INH}$                    | $\pm 0.005$ |                 | $\mu\text{A}$ typ | $V_{IN} = V_{INL}$ or $V_{INH}$   |
|  |             | $\pm 0.1$       | $\mu\text{A}$ max |   |
| Digital Input Capacitance, $C_{IN}$                      | 3           |                 | pF typ            | $f = 1\text{ MHz}$  |
| <b>DYNAMIC CHARACTERISTICS<sup>2</sup></b>               |             |                 |                   |   |
| $T_{ON}$   | 135         |                 | ns typ            | $R_L = 300\ \Omega$ , $C_L = 35\text{ pF}$  |
|  | 170         | 200             | ns max            | $V_S = 8\text{ V}$ ; see Figure 14  |
| $T_{OFF}$  | 95          |                 | ns typ            | $R_L = 300\ \Omega$ , $C_L = 35\text{ pF}$  |
|  | 115         | 140             | ns max            | $V_S = 8\text{ V}$ ; see Figure 14  |
| $T_{BBM}$  | 50          |                 | ns typ            | $R_L = 300\ \Omega$ , $C_L = 35\text{ pF}$  |
|  |             | 10              | ns min            | $V_{S1} = V_{S2} = 8\text{ V}$ ; see Figure 15  |
| Charge Injection   | 2           |                 | pC typ            | $V_S = 6\text{ V}$ , $R_S = 0\ \Omega$ , $C_L = 1\text{ nF}$ ; see Figure 16                                |
| Off Isolation  | 80          |                 | dB typ            | $R_L = 50\ \Omega$ , $C_L = 5\text{ pF}$ , $f = 1\text{ MHz}$ ; see Figure 17                               |
| Channel-to-Channel Crosstalk                             | 85          |                 | dB typ            | $R_L = 50\ \Omega$ , $C_L = 5\text{ pF}$ , $f = 1\text{ MHz}$ ; see Figure 19                               |
| -3 dB Bandwidth  | 500         |                 | MHz typ           | $R_L = 50\ \Omega$ , $C_L = 5\text{ pF}$ ; see Figure 18  |
| $C_S$ (Off)  | 5           |                 | pF typ            | $f = 1\text{ MHz}$ ; $V_S = 6\text{ V}$   |
| $C_D$ (Off)  | 5           |                 | pF typ            | $f = 1\text{ MHz}$ ; $V_S = 6\text{ V}$   |
| $C_D$ , $C_S$ (On)                                       | 10          |                 | pF typ            | $f = 1\text{ MHz}$ ; $V_S = 6\text{ V}$   |
| <b>POWER REQUIREMENTS</b>                                |             |                 |                   |   |
| $I_{DD}$   | 0.002       |                 | $\mu\text{A}$ typ | $V_{DD} = 13.2\text{ V}$<br>Digital inputs = 0 V or $V_{DD}$  |
|  |             | 1               | $\mu\text{A}$ max |   |
| $I_{DD}$   | 260         |                 | $\mu\text{A}$ typ | Digital inputs = 5 V  |
|  |             | 420             | $\mu\text{A}$ max |   |

<sup>1</sup> Temperature range is B Version: -40°C to +105°C.

<sup>2</sup> Guaranteed by design, not subject to production test.

## ABSOLUTE MAXIMUM RATINGS

$T_A = 25^\circ\text{C}$ , unless otherwise noted.

**Table 3.**

| Parameter   | Rating   |
|---|--|
| $V_{DD}$ to $V_{SS}$                                      | 35 V   |
| $V_{DD}$ to GND   | -0.3 V to +25 V  |
| $V_{SS}$ to GND   | +0.3 V to -25 V  |
| Analog, Digital Inputs <sup>1</sup>                       | $V_{SS} - 0.3\text{ V}$ to $V_{DD} + 0.3\text{ V}$<br>or 30 mA, whichever occurs first |
| Continuous Current, S or D                                | 24 mA  |
| Peak Current, S or D (Pulsed at 1 ms, 10% Duty Cycle max) | 100 mA   |
| Operating Temperature Range                               |  |
| Industrial Temperature Range (B Version)                  | -40°C to +105°C  |
| Storage Temperature Range                                 | -65°C to +150°C  |
| Junction Temperature                                      | 150°C  |
| SSOP Package  |  |
| $\theta_{JA}$ , Thermal Impedance                         | 83.2°C/W   |
| Reflow Soldering Peak Temperature, Pb-free                | 260°C  |

<sup>1</sup> Overvoltages at A, EN, S, or D are clamped by internal diodes. Current should be limited to the maximum ratings given.

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those listed in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Only one absolute maximum rating may be applied at any one time.

### ESD CAUTION

ESD (electrostatic discharge) sensitive device. Electrostatic charges as high as 4000 V readily accumulate on the human body and test equipment and can discharge without detection. Although this product features proprietary ESD protection circuitry, permanent damage may occur on devices subjected to high energy electrostatic discharges. Therefore, proper ESD precautions are recommended to avoid performance degradation or loss of functionality.



# ADG1334

## PIN CONFIGURATION AND FUNCTION DESCRIPTIONS

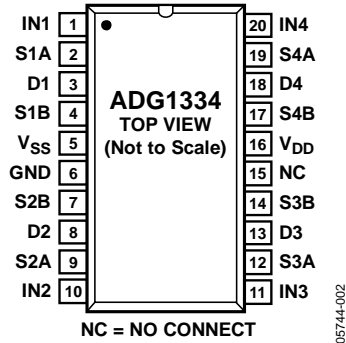


Figure 2. 20-Lead SSOP Pin Configuration

Table 4. 20-Lead SSOP Pin Function Descriptions

| Pin No.                    | Mnemonic                               | Description  |
|----------------------------|--|--|
| 1, 10, 11, 20              | IN1, IN2, IN3, IN4                     | Logic Control Input.   |
| 2, 4, 7, 9, 12, 14, 17, 19 | S1A, S1B, S2B, S2A, S3A, S3B, S4B, S4A | Source Terminal. Can be an input or output.  |
| 3, 8, 13, 18               | D1, D2, D3, D4                         | Drain Terminal. Can be an input or output.   |
| 5                          | V <sub>SS</sub>                        | Most Negative Power Supply Potential in Dual Supplies. In single-supply applications, it can be connected to ground. |
| 6                          | GND                                    | Ground (0 V) Reference.  |
| 15                         | NC                                     | No Connect.  |
| 16                         | V <sub>DD</sub>                        | Most Positive Power Supply Potential.  |

Table 5. ADG1334 Truth Table

| Logic | Switch A | Switch B |
|-------|----------|----------|
| 0     | Off      | On       |
| 1     | On       | Off      |

## TERMINOLOGY

### $R_{ON}$

Ohmic resistance between D and S.

### $\Delta R_{ON}$

Difference between the  $R_{ON}$  of any two channels.

### $I_S$ (Off)

Source leakage current when switch is off.

### $I_D$ (Off)

Drain leakage current when switch is off.

### $I_D, I_S$ (On)

Channel leakage current when switch is on.

### $V_D$ ( $V_S$ )

Analog voltage on Terminal D, Terminal S.

### $C_S$ (OFF)

Channel input capacitance for off condition.

### $C_D$ (Off)

Channel output capacitance for off condition.

### $C_D, C_S$ (On)

On switch capacitance.

### $C_{IN}$

Digital input capacitance.

### $t_{ON}$

The delay between applying the digital control input and the output switching on (see Figure 14).

### $t_{OFF}$

The delay between applying the digital control input and the output switching off (see Figure 14).

### $t_{BBM}$

Off time measured between the 80% point of both switches when switching from one address state to another.

### $V_{INL}$

Maximum input voltage for Logic 0.

### $V_{INH}$

Minimum input voltage for Logic 1.

### $I_{INL}$ ( $I_{INH}$ )

Input current of the digital input.

### $I_{DD}$

Positive supply current.

### $I_{SS}$

Negative supply current.

### Off Isolation

A measure of unwanted signal coupling through an off channel.

### Charge Injection

A measure of the glitch impulse transferred from the digital input to the analog output during switching.

### Bandwidth

Frequency at which the output is attenuated by 3 dB.

### On Response

Frequency response of the on switch.

## TYPICAL PERFORMANCE CHARACTERISTICS

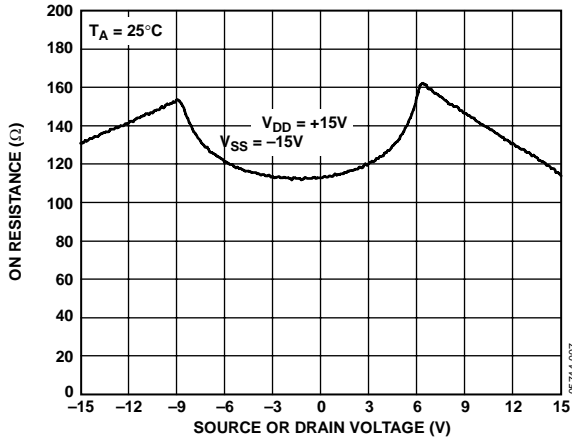


Figure 3. On Resistance as a Function of  $V_D$  ( $V_S$ ) for Dual Supply

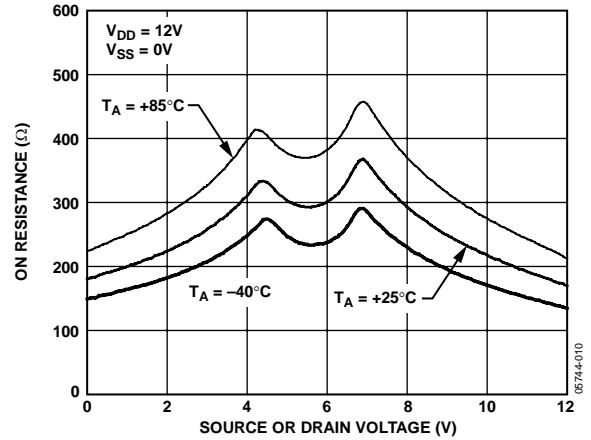


Figure 6. On Resistance as a Function of  $V_D$  ( $V_S$ ) for Different Temperatures, Single Supply

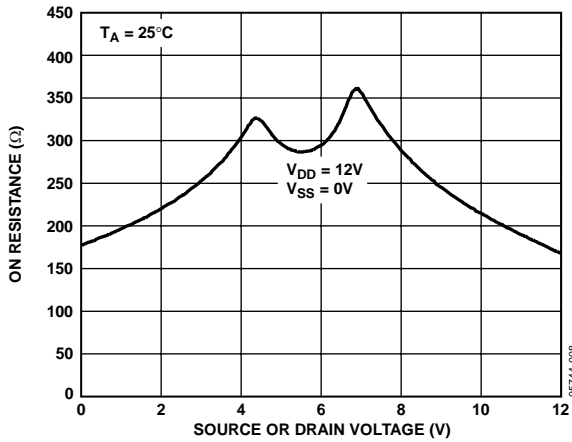


Figure 4. On Resistance as a Function of  $V_D$  ( $V_S$ ) for Single Supply

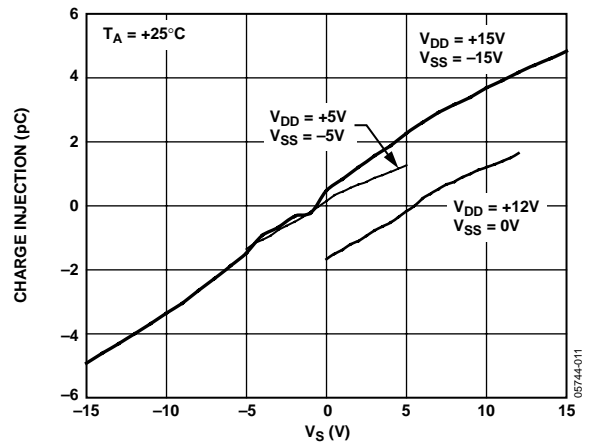


Figure 7. Charge Injection vs. Source Voltage

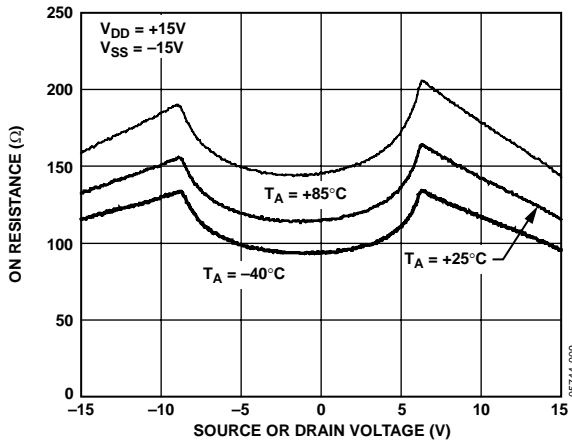


Figure 5. On Resistance as a Function of  $V_D$  ( $V_S$ ) for Different Temperatures, Dual Supply

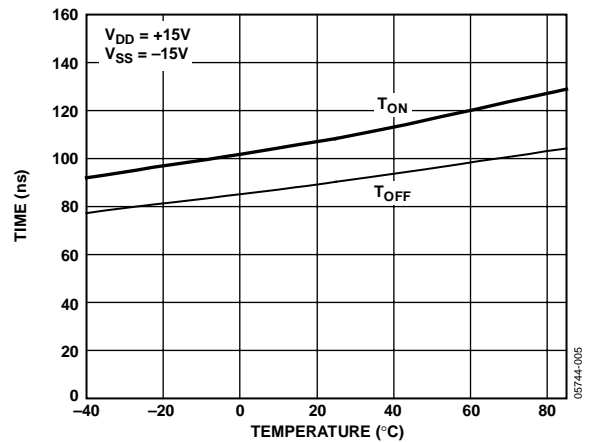


Figure 8.  $T_{ON}/T_{OFF}$  Time vs. Temperature



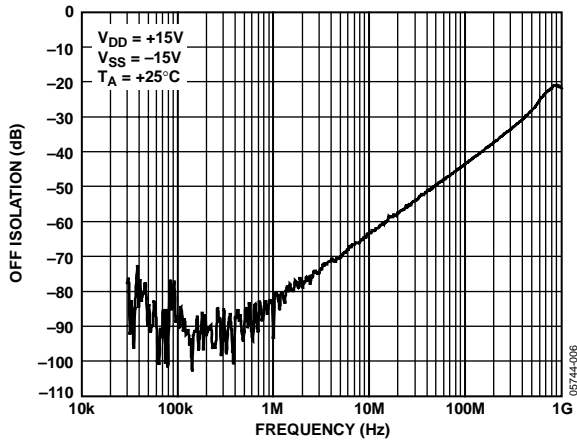


Figure 9. Off Isolation vs. Frequency

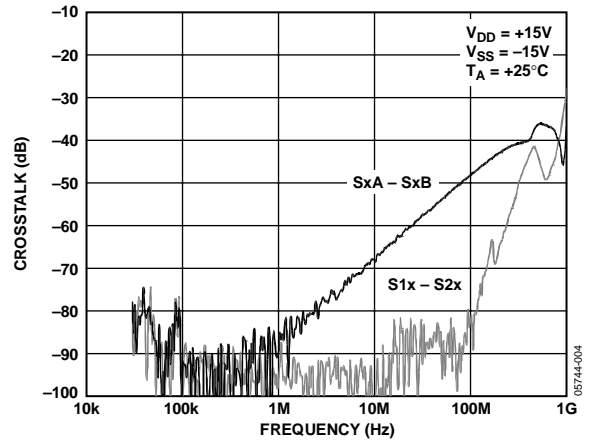


Figure 10. Crosstalk vs. Frequency

TEST CIRCUITS

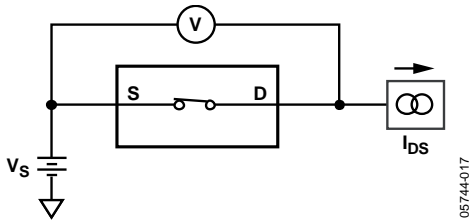


Figure 11. On Resistance

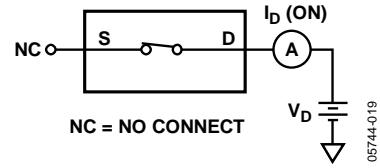


Figure 13. On Leakage

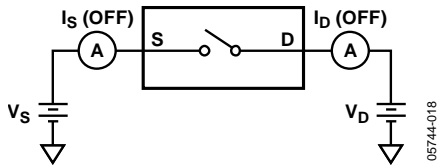


Figure 12. Off Leakage

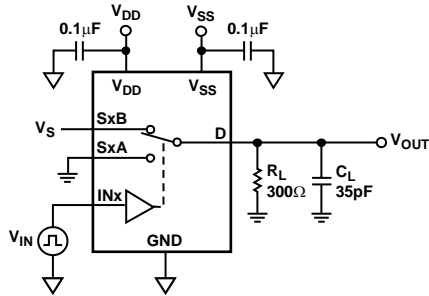


Figure 14. Switching Timing

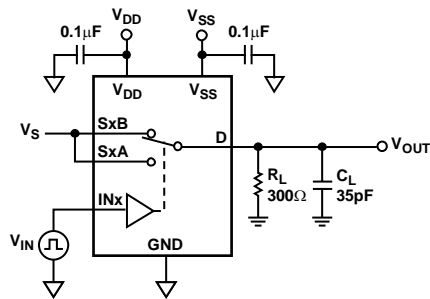
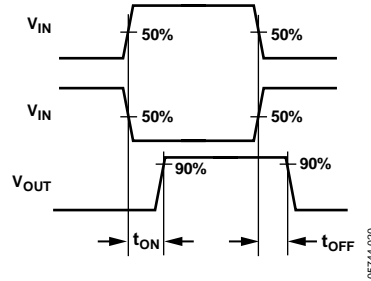
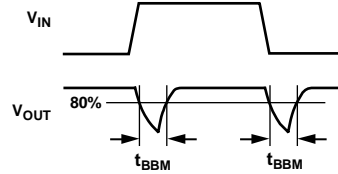


Figure 15. Break-Before-Make Delay



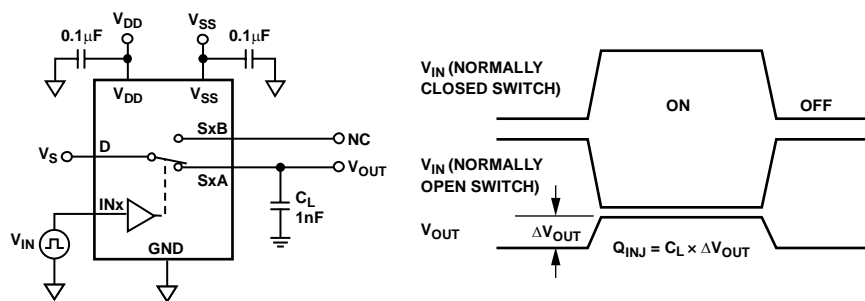


Figure 16. Charge Injection

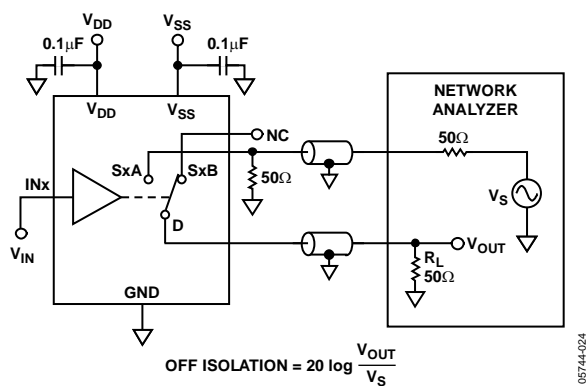


Figure 17. Off Isolation

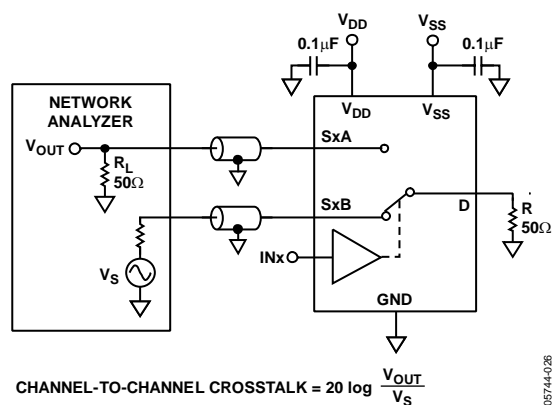


Figure 19. Channel-to-Channel Crosstalk

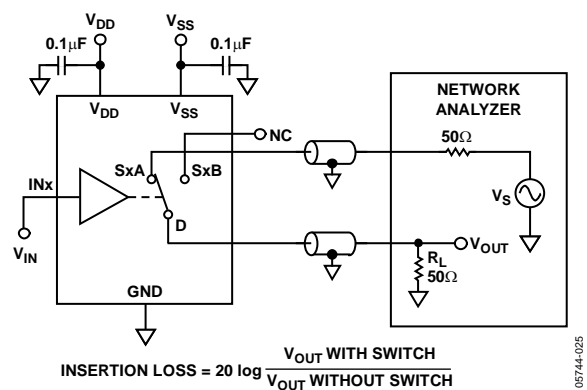
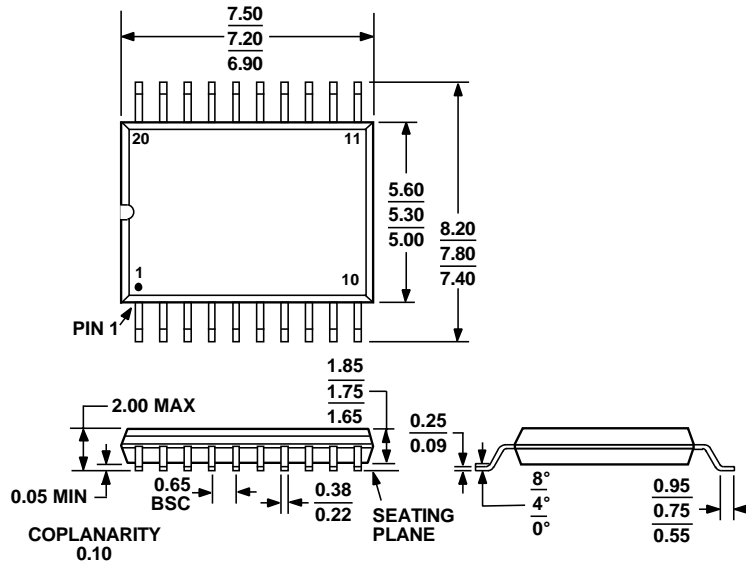


Figure 18. Bandwidth

# ADG1334

## OUTLINE DIMENSIONS



COMPLIANT TO JEDEC STANDARDS MO-150-AE  
 Figure 20. 20-Lead Shrink Small Outline Package [SSOP]  
 (RS-20)

Dimensions shown in millimeters

## ORDERING GUIDE

| Model                         | Temperature Range | Description                                 | Package Option |
|-------------------------------|-------------------|---|----------------|
| ADG1334BRSZ <sup>1</sup>      | -40°C to +105°C   | 20-Lead Shrink Small Outline Package (SSOP) | RS-20          |
| ADG1334BRSZ-REEL <sup>1</sup> | -40°C to +105°C   | 20-Lead Shrink Small Outline Package (SSOP) | RS-20          |

<sup>1</sup> Z = Pb-free part.